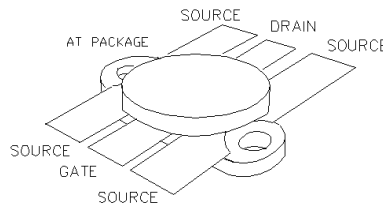




General Description

Silicon VDMOS and LDMOS transistors designed specifically for broadband RF applications. Suitable for Military Radios, Cellular and Paging Amplifier Base Stations, Broadcast FM/AM, MRI, Laser Driver and others.

"Polyfet"™ process features gold metal for greatly extended lifetime. Low output capacitance and high F_t enhance broadband performance



PATENTED GOLD METALIZED SILICON GATE ENHANCEMENT MODE RF POWER VDMOS TRANSISTOR

80 Watts Single Ended

Package Style AT

HIGH EFFICIENCY, LINEAR, HIGH GAIN, LOW NOISE

ABSOLUTE MAXIMUM RATINGS (TC = 25 °C)

Total Device Dissipation	Junction to Case Thermal Resistance	Maximum Junction Temperature	Storage Temperature	DC Drain Current	Drain to Gate Voltage	Drain to Source Voltage	Gate to Source Voltage
190 Watts	0.9 °C/W	200 °C	-65 °C to 150 °C	12 A	50 V	50V	30V

RF CHARACTERISTICS (80WATTS OUTPUT)

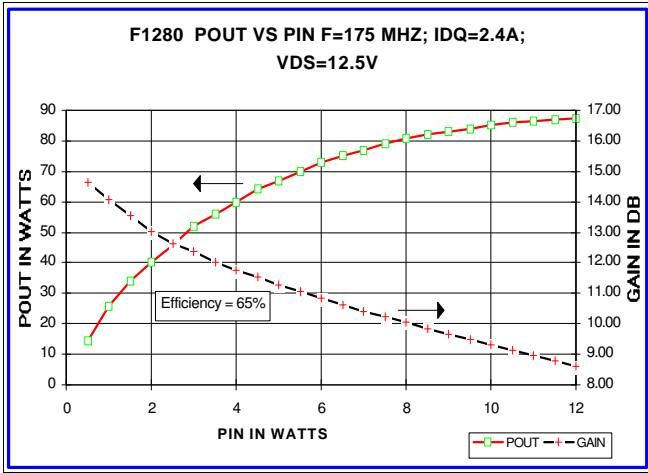
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Gps	Common Source Power Gain	10			dB	$I_{dq} = 2.4 A, V_{ds} = 12.5V, F = 175 MHz$
η	Drain Efficiency		60		%	$I_{dq} = 2.4 A, V_{ds} = 12.5V, F = 175 MHz$
VSWR	Load Mismatch Tolerance			20:1	Relative	$I_{dq} = 2.4 A, V_{ds} = 12.5V, F = 175 MHz$

ELECTRICAL CHARACTERISTICS (EACH SIDE)

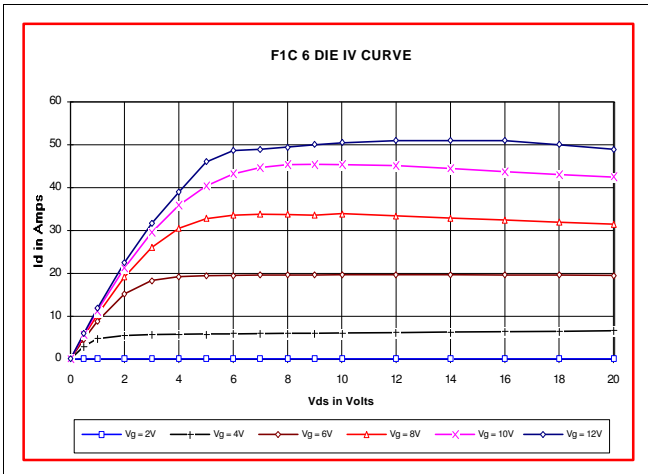
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Bvdss	Drain Breakdown Voltage	40			V	$I_{ds} = 0.3 A, V_{gs} = 0V$
Idss	Zero Bias Drain Current			6	mA	$V_{ds} = 12.5 V, V_{gs} = 0V$
Igss	Gate Leakage Current			1	uA	$V_{ds} = 0 V, V_{gs} = 30V$
Vgs	Gate Bias for Drain Current	1		7	V	$I_{ds} = 0.6 A, V_{gs} = V_{ds}$
gM	Forward Transconductance		4.8		Mho	$V_{ds} = 10V, V_{gs} = 5V$
Rdson	Saturation Resistance		0.15		Ohm	$V_{gs} = 20V, I_{ds} = 48A$
Idsat	Saturation Current		45		Amp	$V_{gs} = 20V, V_{ds} = 10V$
Ciss	Common Source Input Capacitance		240		pF	$V_{ds} = 12.5 V, V_{gs} = 0V, F = 1 MHz$
Crss	Common Source Feedback Capacitance		36		pF	$V_{ds} = 12.5 V, V_{gs} = 0V, F = 1 MHz$
Coss	Common Source Output Capacitance		180		pF	$V_{ds} = 12.5 V, V_{gs} = 0V, F = 1 MHz$

F1280

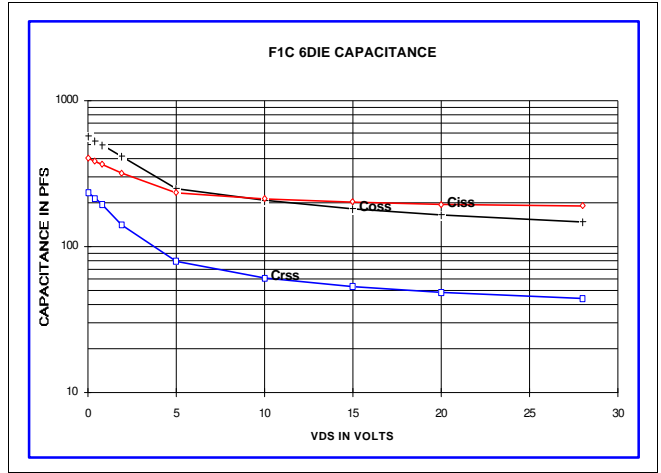
POUT VS PIN GRAPH



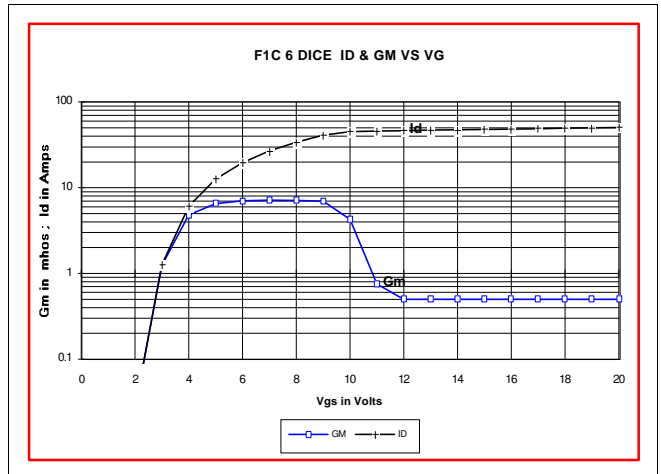
IV CURVE



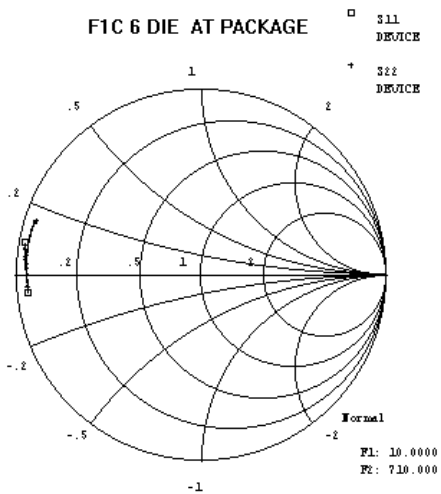
CAPACITANCE VS VOLTAGE



ID AND GM VS VGS



S11 AND S22 SMITH CHART



PACKAGE DIMENSIONS IN INCHES

